# **General Purpose Transistor**

## **NPN Silicon**

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-416/SC-75 package which is designed for low power surface mount applications.

#### **Features**

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Rating	Symbol	Max	Unit
Collector–Emitter Voltage	V <sub>CEO</sub>	40	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	75	Vdc
Emitter–Base Voltage	V <sub>EBO</sub>	6.0	Vdc
Collector Current – Continuous	Ic	600	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation (Note 1) $T_A = 25^{\circ}C$	P <sub>D</sub>	150	mW
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	833	°C/W
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

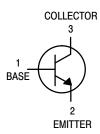
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

 Device mounted on FR4 glass epoxy printed circuit board using the minimum recommended footprint.



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CASE 463 SOT-416/SC-75 STYLE 1

#### **MARKING DIAGRAM**



1P = Specific Device Code

M = Date Code ■ Pb–Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBT2222ATT1G	SOT-416 (Pb-Free)	3000 / Tape & Reel
NSVMMBT2222ATT1G	SOT-416 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

## FI FCTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Charac	Symbol	Min	Max	Unit		
OFF CHARACTERISTICS				•		
Collector – Emitter Breakdown Voltage (Not $(I_C = 10 \text{ mAdc}, I_B = 0)$	e 1)	V <sub>(BR)CEO</sub>	40	_	Vdc	
Collector – Base Breakdown Voltage ( $I_C = 10 \mu Adc, I_E = 0$ )		V <sub>(BR)CBO</sub>	75	_	Vdc	
Emitter-Base Breakdown Voltage ( $I_E = 10 \mu Adc$ , $I_C = 0$ )		V <sub>(BR)EBO</sub>	6.0	_	Vdc	
Base Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>EB</sub> = 3.0 Vdc)		I <sub>BL</sub>	-	20	nAdc	
Collector Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>EB</sub> = 3.0 Vdc)		I <sub>CEX</sub>	-	10	nAdc	
ON CHARACTERISTICS (Note 2)						
DC Current Gain $ \begin{aligned} &(I_C=0.1 \text{ mAdc, } V_{CE}=10 \text{ Vdc}) \\ &(I_C=1.0 \text{ mAdc, } V_{CE}=10 \text{ Vdc}) \\ &(I_C=10 \text{ mAdc, } V_{CE}=10 \text{ Vdc}) \\ &(I_C=150 \text{ mAdc, } V_{CE}=10 \text{ Vdc}) \\ &(I_C=500 \text{ mAdc, } V_{CE}=10 \text{ Vdc}) \end{aligned} $		H <sub>FE</sub>	35 50 75 100 40	- - - -	_	
Collector – Emitter Saturation Voltage ( $I_C = 150 \text{ mAdc}$ , $I_B = 15 \text{ mAdc}$ ) ( $I_C = 500 \text{ mAdc}$ , $I_B = 50 \text{ mAdc}$ )		V <sub>CE(sat)</sub>	- -	0.3 1.0	Vdc	
Base – Emitter Saturation Voltage ( $I_C = 150 \text{ mAdc}$ , $I_B = 15 \text{ mAdc}$ ) ( $I_C = 500 \text{ mAdc}$ , $I_B = 50 \text{ mAdc}$ )	V <sub>BE(sat)</sub>	0.6	1.2 2.0	Vdc		
SMALL-SIGNAL CHARACTERISTICS						
Current-Gain - Bandwidth Product (I <sub>C</sub> = 20 mAdc, V <sub>CE</sub> = 20 Vdc, f = 100 MH	Hz)	f <sub>T</sub>	300	_	MHz	
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>obo</sub>	-	8.0	pF		
Input Capacitance (V <sub>EB</sub> = 0.5 Vdc, I <sub>C</sub> = 0, f = 1.0 MHz)	C <sub>ibo</sub>	-	30	pF		
Input Impedance ( $V_{CE} = 10 \text{ Vdc}$ , $I_{C} = 10 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$	h <sub>ie</sub>	0.25	1.25	kΩ		
Voltage Feedback Ratio $(V_{CE} = 10 \text{ Vdc}, I_{C} = 10 \text{ mAdc}, f = 1.0 \text{ kHz}$	h <sub>re</sub>	-	4.0	X 10 <sup>-4</sup>		
Small – Signal Current Gain (V <sub>CE</sub> = 10 Vdc, I <sub>C</sub> = 10 mAdc, f = 1.0 kHz	h <sub>fe</sub>	75	375	_		
Output Admittance ( $V_{CE} = 10 \text{ Vdc}$ , $I_{C} = 10 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$	h <sub>oe</sub>	25	200	μmhos		
Noise Figure ( $V_{CE} = 10 \text{ Vdc}, I_C = 100 \mu Adc, R_S = 1.0 $	NF	-	4.0	dB		
SWITCHING CHARACTERISTICS				•	•	
Delay Time	$(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = -0.5 \text{ Vdc},$	t <sub>d</sub>	-	10	no	
Rise Time	$I_C = 150 \text{ mAdc}, I_{B1} = 15 \text{ mAdc})$	t <sub>r</sub>		25	ns	
Storage Time	$(V_{CC} = 30 \text{ Vdc}, I_C = 150 \text{ mAdc}, I_{B1} = I_{B2} = 15 \text{ mAdc})$	ts	-	225	ns	
Fall Time	t <sub>f</sub>	-	60			

Device mounted on FR4 glass epoxy printed circuit board using the minimum recommended footprint.
 Pulse Test: Pulse Width ≤ 300 µs, Duty Cycle ≤ 2.0%.

### **SWITCHING TIME EQUIVALENT TEST CIRCUITS**

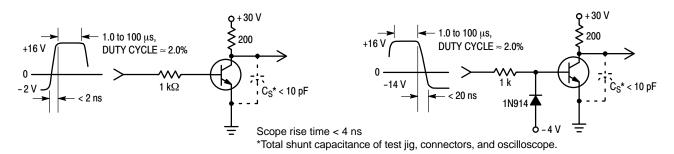


Figure 1. Turn-On Time

Figure 2. Turn-Off Time

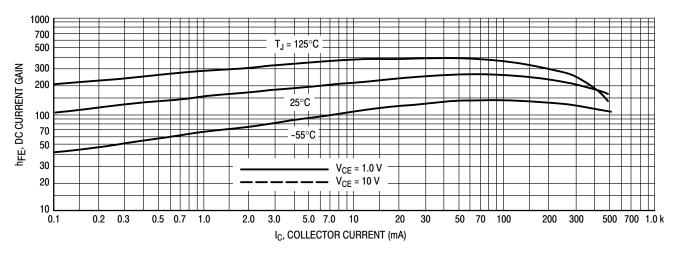


Figure 3. DC Current Gain

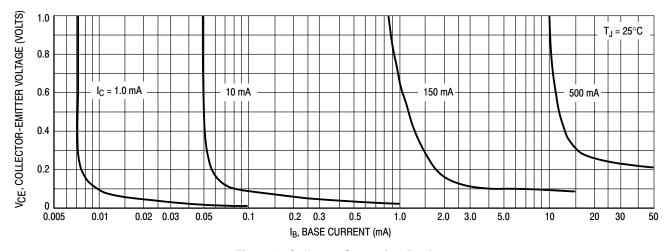


Figure 4. Collector Saturation Region

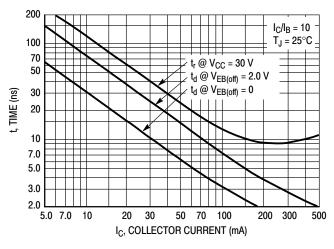


Figure 5. Turn - On Time

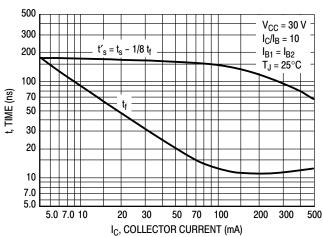


Figure 6. Turn-Off Time

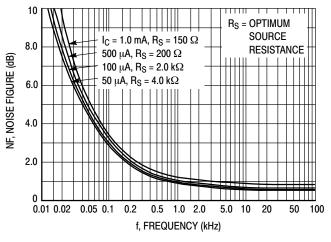
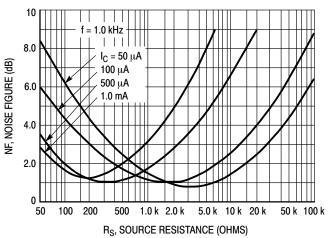


Figure 7. Frequency Effects



**Figure 8. Source Resistance Effects** 

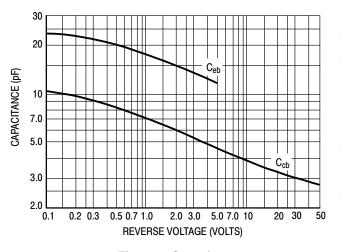


Figure 9. Capacitances

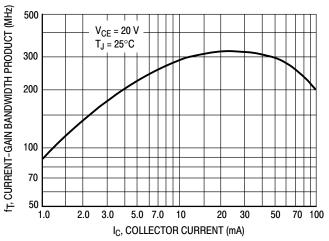


Figure 10. Current-Gain Bandwidth Product

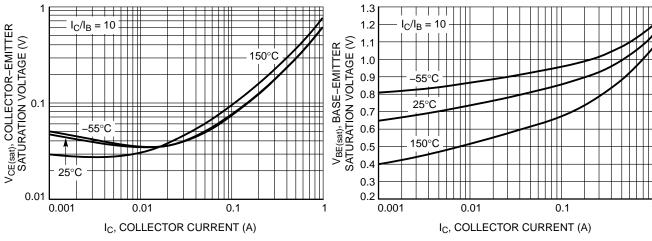


Figure 11. Collector Emitter Saturation Voltage vs. Collector Current

Figure 12. Base Emitter Saturation Voltage vs. Collector Current

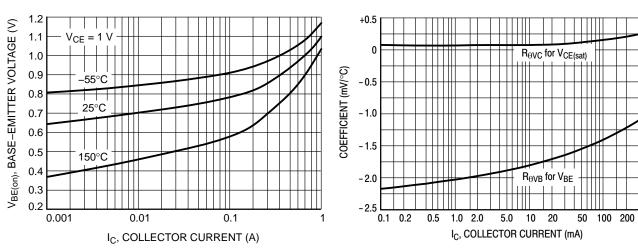


Figure 13. Base Emitter Voltage vs. Collector Current

**Figure 14. Temperature Coefficients** 

500

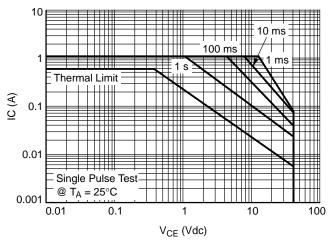


Figure 15. Safe Operating Area

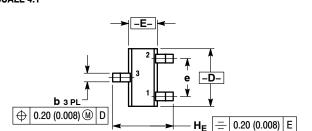
## **MECHANICAL CASE OUTLINE**

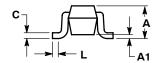




SC-75/SOT-416 CASE 463-01 ISSUE G

**DATE 07 AUG 2015** 





STYLE 1: PIN 1. BASE 2. EMITTER

STYLE 4:

3. COLLECTOR

PIN 1. CATHODE 2. CATHODE 3. ANODE

STYLE 5: PIN 1. GATE 2. SOURCE

3. DRAIN

STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE

STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

		MILLIMETERS			INCHES		
DII	И	MIN	NOM	MAX	MIN	NOM	MAX
Α		0.70	0.80	0.90	0.027	0.031	0.035
A	1	0.00	0.05	0.10	0.000	0.002	0.004
b		0.15	0.20	0.30	0.006	0.008	0.012
С		0.10	0.15	0.25	0.004	0.006	0.010
D		1.55	1.60	1.65	0.061	0.063	0.065
E		0.70	0.80	0.90	0.027	0.031	0.035
е		1.00 BSC			C	0.04 BSC	)
L		0.10	0.15	0.20	0.004	0.006	0.008
HE	:	1.50	1.60	1.70	0.060	0.063	0.067

### **GENERIC MARKING DIAGRAM\***

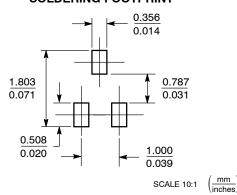


XX= Specific Device Code

Μ = Date Code

= Pb-Free Package

## **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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<sup>\*</sup>This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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